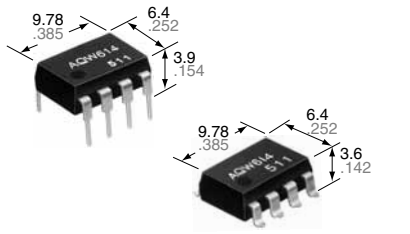
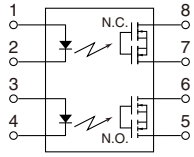
Both NO and NC contacts incorporated in a DIP8-pin package

PhotoMOS®
GU 1 Form A & 1 Form B
(AQW614)



mm inch



RoHS compliant

FEATURES

1. Approx. 1/2 the space compared with the mounting of a set of 1 Form A and 1 Form B PhotoMOS
2. Applicable for 1 Form A and 1 Form B use as well as two independent 1 Form A and 1 Form B use
3. Controls load currents up to 0.13 A with 5 mA input current
4. Extremely low closed-circuit offset voltages to enable control of small analog signals without distortion
5. Stable on-resistance

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Computers
- Sensing equipment

TYPES

	Output rating*		Package	Part No.				Packing quantity	
	Load voltage	Load current		Through hole terminal	Surface-mount terminal				
				Tube packing style		Tape and reel packing style		Tube	Tape and reel
						Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC dual use	400 V	100 mA	DIP8-pin	AQW614	AQW614A	AQW614AX	AQW614AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.

*Indicate the peak AC and DC values.
Note: The surface mount terminal shape indicator “A” and the packing style indicator “X” or “Z” are not marked on the device.

RATING

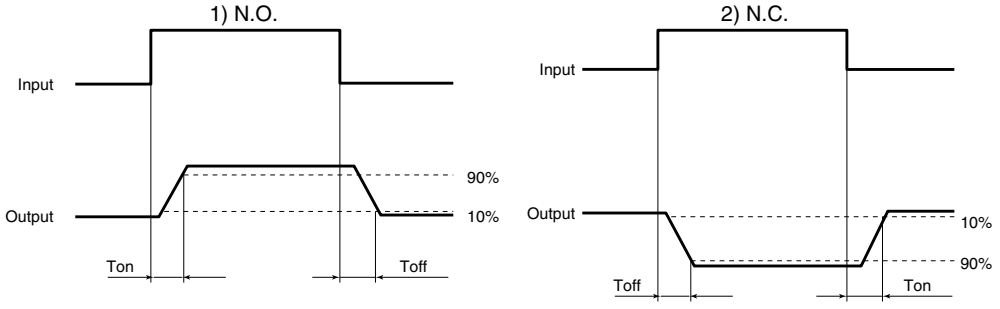
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW614(A)	Remarks
Input	LED forward current	I_F	50 mA	
	LED reverse voltage	V_R	5 V	
	Peak forward current	I_{FP}	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P_{in}	75 mW	
Output	Load voltage (peak AC)	V_L	400 V	
	Continuous load current	I_L	0.1 A (0.13 A)	Peak AC, DC ( ): in case of using only 1a or 1b, 1 channel
	Peak load current	I_{peak}	0.3 A	100 ms (1 shot), V_L = DC
	Power dissipation	P_{out}	800 mW	
Total power dissipation		P_T	850 mW	
I/O isolation voltage		V_{iso}	1,500 V AC	Between input and output/between contact sets
Temperature limits	Operating	T_{opr}	–40°C to +85°C –40°F to +185°F	Non-condensing at low temperatures
	Storage	T_{stg}	–40°C to +100°C –40°F to +212°F	

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQW614(A)	Condition
Input	LED operate current	Typical	I_{Fon} (N.O.) I_{Foff} (N.C.)	0.9 mA	I_L = 100 mA
		Maximum		3 mA	
	LED reverse current	Minimum	I_{Foff} (N.O.) I_{Fon} (N.C.)	0.4 mA	I_L = 100 mA
		Typical		0.8 mA	
	LED dropout voltage	Typical	V_F	1.25 V (1.14 V at I_F = 5 mA)	I_F = 50 mA
		Maximum		1.5 V	
Output	On resistance	Typical	R_{on}	27 Ω	I_F = 5 mA (N.O.) I_F = 0 mA (N.C.) I_L = 100 mA within 1 s on time
		Maximum		50 Ω	
	Off state leakage current	Maximum	I_{Leak}	1 μA	I_F = 0 mA (N.O.) I_F = 5 mA (N.C.) V_L = 400 V
Transfer characteristics	Operate time*	Typical	T_{on} (N.O.) T_{off} (N.C.)	0.28 ms (N.O.) 0.43 ms (N.C.)	I_F = 0 mA → 5 mA I_L = 100 mA
		Maximum		1 ms	
	Reverse time*	Typical	T_{off} (N.O.) T_{on} (N.C.)	0.04 ms (N.O.) 0.3 ms (N.C.)	I_F = 5 mA → 0 mA I_L = 100 mA
		Maximum		1 ms	
	I/O capacitance	Typical	C_{iso}	0.8 pF	f = 1 MHz V_B = 0 V
		Maximum		1.5 pF	
	Initial I/O isolation resistance	Minimum	R_{iso}	1,000 MΩ	500 V DC

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

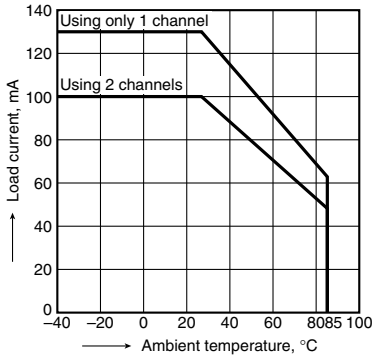
Item	Symbol	Recommended value	Unit
Input LED current	I_F	5	mA

■ **These products are not designed for automotive use.**
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

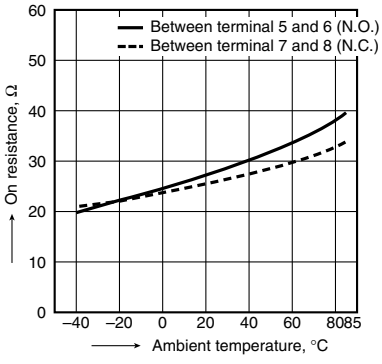
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: –40°C to +85°C
–40°F to +185°F



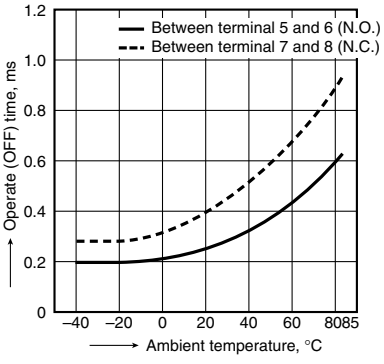
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 5 mA; Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



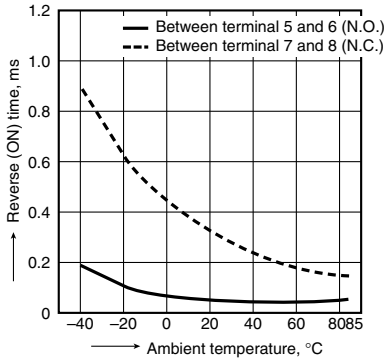
3. Operate time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



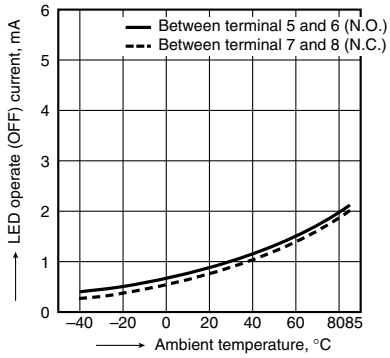
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



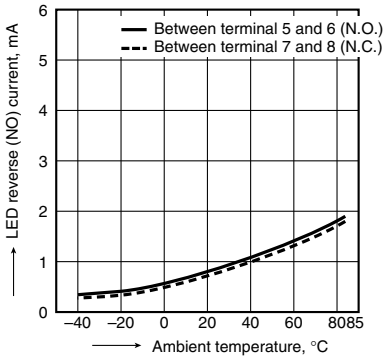
5. LED operate current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



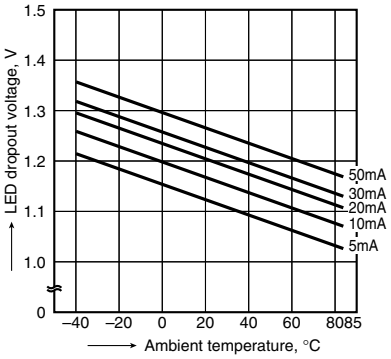
6. LED reverse current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



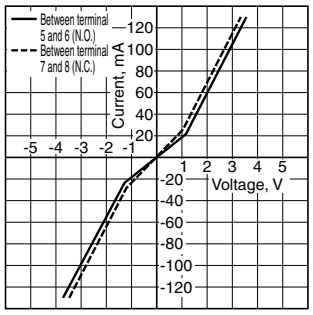
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



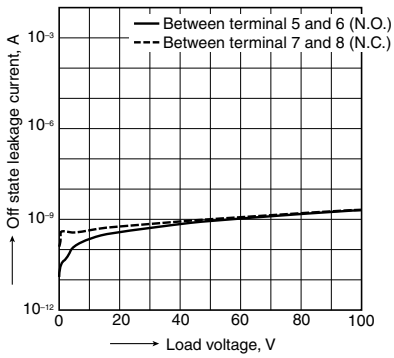
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



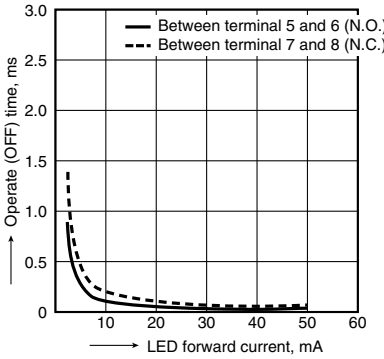
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



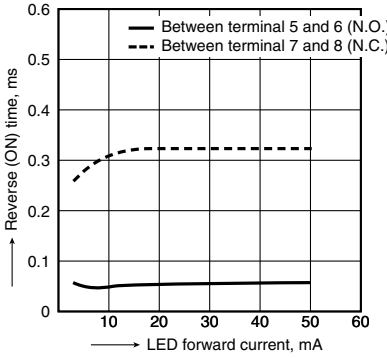
10. Operate time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: 400 V (DC); Continuous load current:
100 mA (DC); Ambient temperature: 25°C 77°F



11. Reverse time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: 400 V (DC); Continuous load current:
100 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 0 mA (N.O.), 5 mA (N.C.); Frequency:
1 MHz; Ambient temperature: 25°C 77°F